

# 4.5V Drive Nch MOSFET

## RMW200N03

● **Structure**

Silicon N-channel MOSFET

● **Features**

- 1) High Power package(PSOP8).
- 2) High-speed switching,Low On-resistance.
- 3) Low voltage drive(4.5V drive).

● **Application**

Switching

● **Packaging specifications**

Type	Package	Taping
	Code	TB
	Basic ordering unit (pieces)	2500
RMW200N03		O

● **Absolute maximum ratings (Ta = 25°C)**

Parameter	Symbol	Limits	Unit	
Drain-source voltage	V <sub>DSS</sub>	30	V	
Gate-source voltage	V <sub>GSS</sub>	±20	V	
Drain current	Continuous	I <sub>D</sub>	±20	A
	Pulsed	I <sub>DP</sub> *1	±80	A
Source current (Body Diode)	Continuous	I <sub>S</sub>	2.5	A
	Pulsed	I <sub>SP</sub> *1	80	A
Power dissipation	P <sub>D</sub> *2	3.0	W	
Channel temperature	T <sub>ch</sub>	150	°C	
Range of storage temperature	T <sub>stg</sub>	-55 to +150	°C	

\*1 Pw≤10μs, Duty cycle≤1%

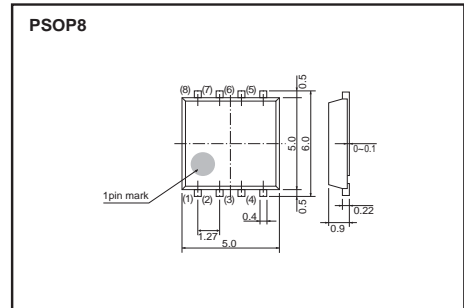
\*2 MOUNTED ON 40mm × 40mm Cu BOARD

● **Thermal resistance**

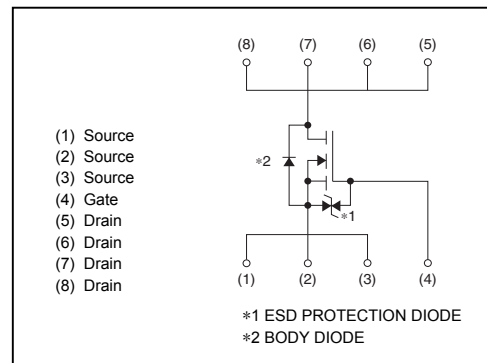
Parameter	Symbol	Limits	Unit
Channel to Ambient	R <sub>th (ch-a)</sub> *	41.7	°C / W

\* MOUNTED ON 40mm × 40mm Cu BOARD

● **Dimensions (Unit : mm)**



● **Inner circuit**



**● Electrical characteristics (Ta = 25°C)**

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	$I_{GSS}$	-	-	$\pm 10$	$\mu A$	$V_{GS}=\pm 20V, V_{DS}=0V$
Drain-source breakdown voltage	$V_{(BR)DSS}$	30	-	-	V	$I_D=1mA, V_{GS}=0V$
Zero gate voltage drain current	$I_{DSS}$	-	-	1	$\mu A$	$V_{DS}=30V, V_{GS}=0V$
Gate threshold voltage	$V_{GS(th)}$	1.0	-	2.5	V	$V_{DS}=10V, I_D=1mA$
Static drain-source on-state resistance	$R_{DS(on)}^*$	-	3.0	4.2	m $\Omega$	$I_D=20A, V_{GS}=10V$
		-	4.0	5.6		$I_D=20A, V_{GS}=4.5V$
Forward transfer admittance	$ Y_{fs} ^*$	20	-	-	S	$I_D=20A, V_{DS}=10V$
Input capacitance	$C_{ISS}$	-	1780	-	pF	$V_{DS}=15V$
Output capacitance	$C_{OSS}$	-	580	-	pF	$V_{GS}=0V$
Reverse transfer capacitance	$C_{RSS}$	-	210	-	pF	$f=1MHz$
Turn-on delay time	$t_{d(on)}^*$	-	18	-	ns	$I_D=10A, V_{DD} \approx 15V$
Rise time	$t_r^*$	-	50	-	ns	$V_{GS}=10V$
Turn-off delay time	$t_{d(off)}^*$	-	60	-	ns	$R_L=1.5\Omega$
Fall time	$t_f^*$	-	20	-	ns	$R_G=10\Omega$
Total gate charge	$Q_g^*$	-	29	-	nC	$I_D=20A, V_{DD} \approx 15V$
Gate-source charge	$Q_{gs}^*$	-	5.7	-	nC	$V_{GS}=10V$
Gate-drain charge	$Q_{gd}^*$	-	5.5	-	nC	

\*Pulsed

**● Body diode characteristics (Source-Drain) (Ta = 25°C)**

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward Voltage	$V_{SD}^*$	-	-	1.2	V	$I_S=2.5A, V_{GS}=0V$

\*Pulsed

●Electrical characteristic curves (Ta=25°C)

Fig.1 Typical Output Characteristics ( I )

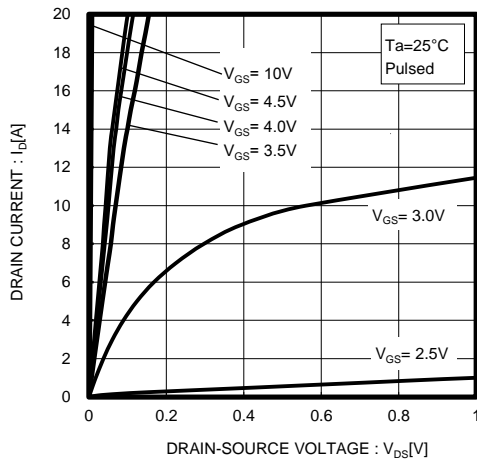


Fig.2 Typical Output Characteristics ( II )

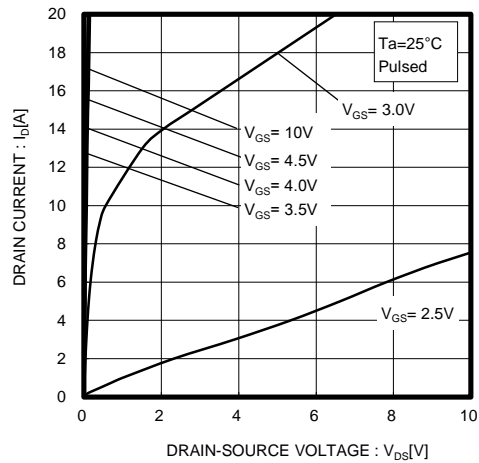


Fig.3 Typical Transfer Characteristics

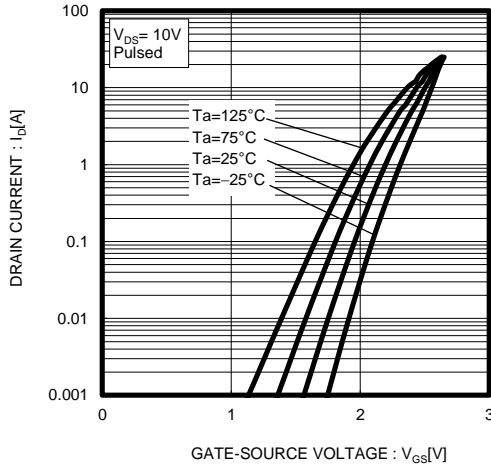


Fig.4 Static Drain-Source On-State Resistance vs. Drain Current ( I )

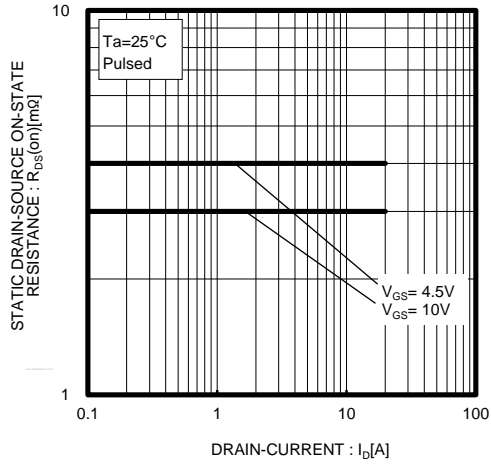


Fig.5 Static Drain-Source On-State Resistance vs. Drain Current ( II )

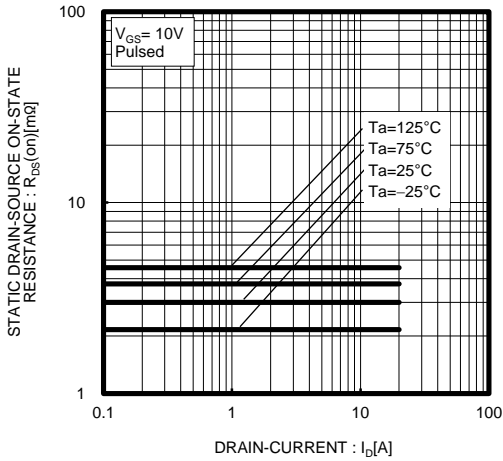


Fig.6 Static Drain-Source On-State Resistance vs. Drain Current ( III )

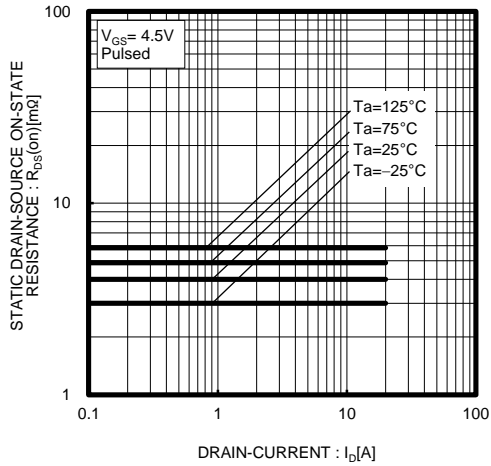


Fig.7 Forward Transfer Admittance vs. Drain Current

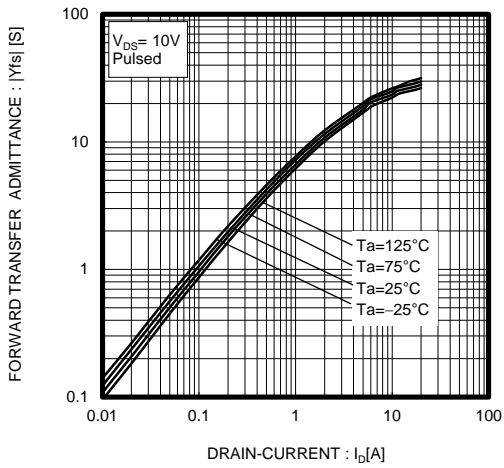


Fig.8 Reverse Drain Current vs. Source-Drain Voltage

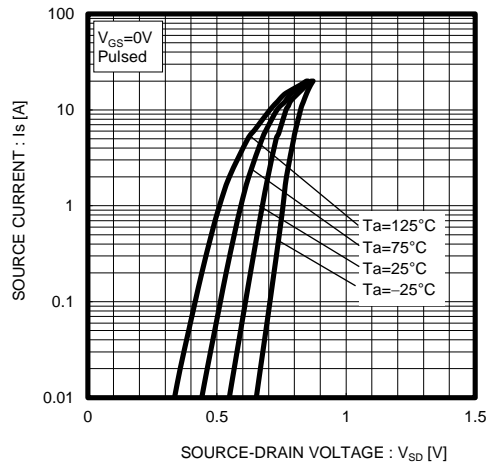


Fig.9 Static Drain-Source On-State Resistance vs. Gate Source Voltage

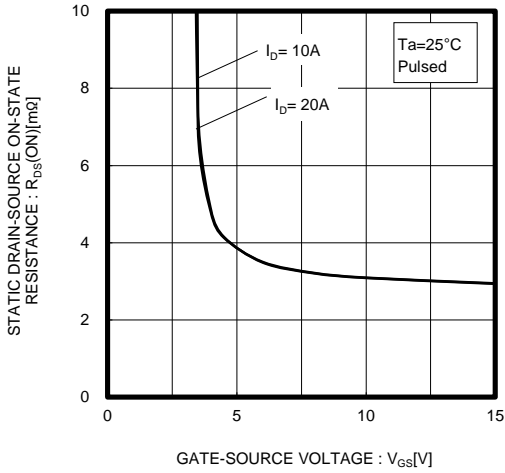


Fig.10 Switching Characteristics

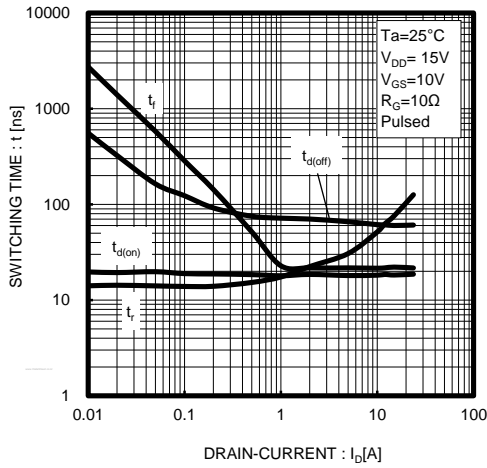


Fig.11 Dynamic Input Characteristics

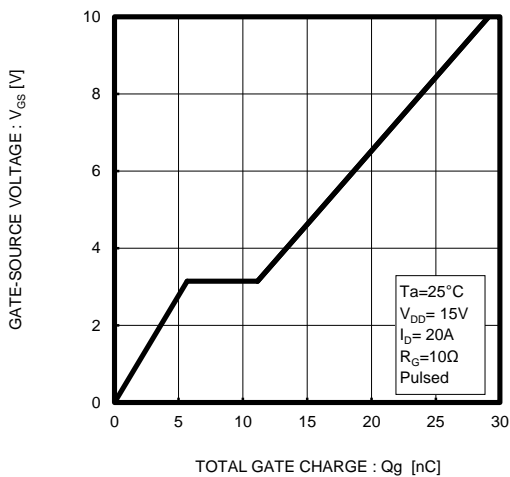


Fig.12 Typical Capacitance vs. Drain-Source Voltage

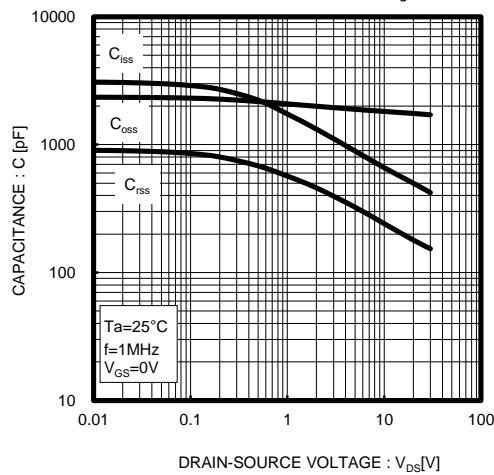


Fig.13 Maximum Safe Operating Area

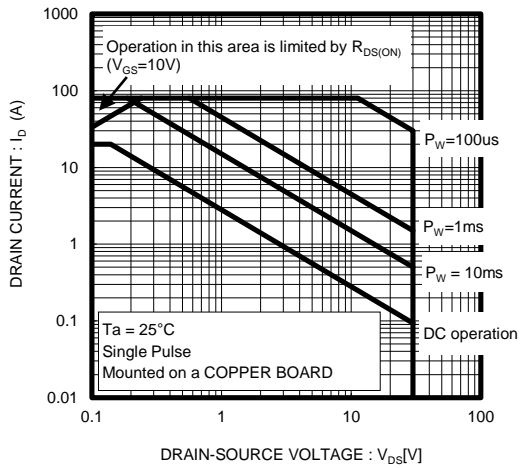
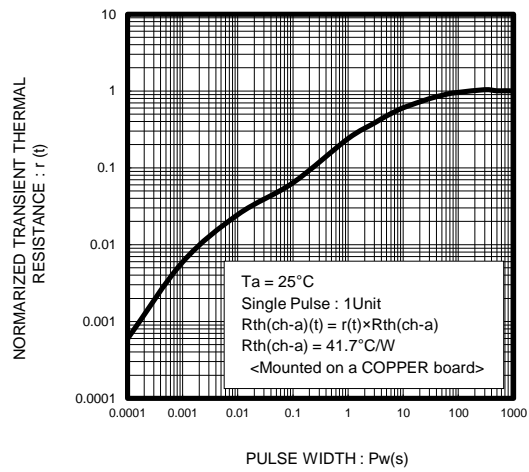


Fig.14 Normalized Transient Thermal Resistance vs. Pulse Width



● Measurement circuits

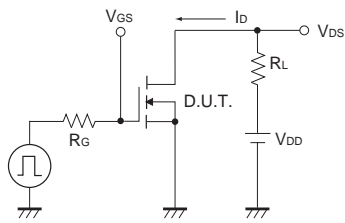


Fig.1-1 Switching Time Measurement Circuit

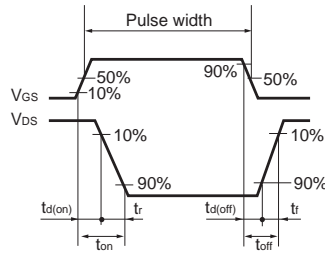


Fig.1-2 Switching Waveforms

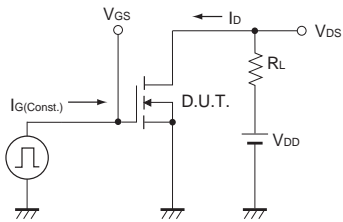


Fig.2-1 Gate Charge Measurement Circuit

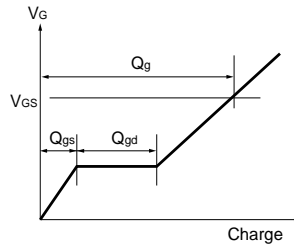


Fig.2-2 Gate Charge Waveform

● Notice

This product might cause chip aging and breakdown under the large electrified environment. Please consider to design ESD protection circuit.

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